



# **PNP POWER SILICON TRANSISTOR**

Qualified per MIL-PRF-19500/535

### DESCRIPTION

This high speed transistor is rated at 5 amps and is military qualified up to a JANTXV level. This TO-59 isolated package is available with a 180 degree lead orientation. Microsemi also offers numerous other products to meet higher and lower power voltage regulation applications.

Important: For the latest information, visit our website http://www.microsemi.com.

FEATURES

- JEDEC registered 2N5003 and 2N5005.
- Internal metallurgical bond option available.
- JAN, JANTX, and JANTXV, qualification per MIL-PRF-19500/535 available.
- RoHS compliant versions available (commercial grade only).

### **APPLICATIONS / BENEFITS**

- Fast switching capable 0.5  $\mu$ s rise time.
- High frequency response.
- TO-59 case with Isolated terminals.
- Class 3B to ESD per MIL-STD-750 Method 1020.

### **MAXIMUM RATINGS**

Parameters/Test Conditions	Symbol	Value	Unit
Junction and Storage Temperature	$T_J$ and $T_{STG}$	-65 to +200	°C
Thermal Resistance Junction-to-Ambient	R <sub>eja</sub>	88	°C/W
Thermal Resistance Junction-to-Case	R <sub>eJC</sub>	3.0	°C/W
Collector Current	lc	5.0	А
	Ic <sup>(3)</sup>	10	
Collector-Emitter Voltage	V <sub>CEO</sub>	80	V
Collector-Base Voltage	V <sub>CBO</sub>	100	V
Emitter-Base Voltage	V <sub>EBO</sub>	5.5	V
Steady-State Power Dissipation $@T_A = +25^{\circ}C^{(1)}$	PD	2.0	W
$@ T_{c} = +25^{\circ}C^{(2)}$		58	

**Notes:** 1. Derate linearly 11.4 mW/°C for  $T_A > +25^{\circ}C$ .

- 2. Derate linearly 331 mW/°C for  $T_c > +25^{\circ}C$ .
  - 3. This value applies for PW  $\leq$  8.3 ms, duty cycle  $\leq$  1%.

<u>Qualified Levels:</u> JAN, JANTX, and JANTXV



Marking may vary.

# TO-59 (TO-210AA) Isolated Package

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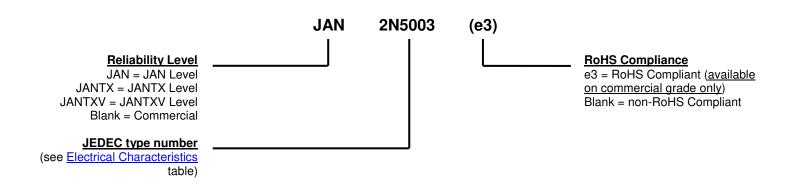
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# MECHANICAL and PACKAGING

- CASE: Nickel Plated.
- TERMINALS: Solder Dip over Nickel Plating. RoHS compliant Matte/Tin available on commercial grade only.
- MARKING: Manufacturer's ID, Date Code, Part Number, BeO.
- POLARITY: See Package Outline Drawing on last page.
- See <u>Package Dimensions</u> on last page.

# PART NOMENCLATURE



SYMBOLS & DEFINITIONS				
Symbol	Definition			
C <sub>obo</sub>	Common-base open-circuit output capacitance.			
I <sub>CEO</sub>	Collector cutoff current, base open.			
I <sub>CES</sub>	Collector emitter cutoff current, circuit between base and emitter.			
I <sub>EBO</sub>	Emitter cutoff current, collector open.			
h <sub>FE</sub>	Common-emitter static forward current transfer ratio.			
V <sub>CEO</sub>	Collector-emitter voltage, base open.			
V <sub>CBO</sub>	Collector-emitter voltage, emitter open.			
V <sub>EBO</sub>	Emitter-base voltage, collector open.			



Characteristic		Symbol	Min.	Max.	Unit
OFF CHARACTERISTICS Collector-Emitter Breakdown Voltage					
$l_{\rm C} = 100  {\rm mA}$		$V_{(BR)CEO}$	80		V
Collector-Emitter Cutoff Current					
$V_{CE} = 40 \text{ V}, \text{ I}_{B} = 0$		I <sub>CEO</sub>		50	μA
Collector-Emitter Cutoff Current				1.0	
$V_{CE} = 60 V, V_{BE} = 0$		I <sub>CES</sub>		1.0 1.0	μA mA
$V_{CE} = 100 V, V_{BE} = 0$				1.0	mA
Emitter-Base Cutoff Current				1.0 1.0	μA
$V_{BE} = 4.0 V, I_{C} = 0$		I <sub>EBO</sub>			mA
$V_{BE} = 5.5 \text{ V}, I_{C} = 0$			1.0		
N CHARACTERISTICS					
Forward-Current Transfer Ratio					
$I_{C} = 50 \text{ mA}, V_{CE} = 5.0 \text{ V}$	2N5003	h <sub>FE</sub>	20		
I <sub>C</sub> = 2.5 A, V <sub>CE</sub> = 5.0 V			30	90	
$I_{C} = 5.0 \text{ A}, V_{CE} = 5.0 \text{ V}$			20		
$I_{\rm C} = 50$ mA, $V_{\rm CE} = 5.0$ V	2N5005		50		
$I_{\rm C} = 2.5 \text{ A}, V_{\rm CF} = 5.0 \text{ V}$			70	200	
$I_{\rm C} = 5.0 \text{ A}, V_{\rm CE} = 5.0 \text{ V}$			40		
Base-Emitter Voltage Non-saturated					
$V_{CE} = 5.0 \text{ V}, \text{ I}_{C} = 2.5 \text{ A}$		V <sub>BE</sub>		1.45	V
Collector-Emitter Saturation Voltage					
I <sub>C</sub> = 2.5 A, I <sub>B</sub> = 250 mA		V <sub>CE(sat)</sub>		0.75	V
$I_{\rm C} = 5.0$ A, $I_{\rm B} = 500$ mA				1.5	
Base-Emitter Saturation Voltage					
$I_{\rm C} = 2.5 \text{ A}, I_{\rm B} = 250 \text{ mA}$		V <sub>BE(sat)</sub>		1.45	V
$I_{\rm C} = 5.0 \text{ A}, I_{\rm B} = 500 \text{ mA}$				2.2	
YNAMIC CHARACTERISTICS					
Common Emitter Small-Signal Short-Circuit		h			
Forward Current Transfer Ratio	2N5003	h <sub>fe</sub>	20		
$I_C = 100 \text{ mA}, V_{CE} = 5.0 \text{ V}, f = 1 \text{ kHz}$	2N5005		50		
Magnitude of Common Emitter Small-Signal Sho	ort-Circuit				
0		10.1		1	1
Forward Current Transfer Ratio $I_C = 500 \text{ mA}, V_{CE} = 5.0 \text{ V}, f = 10 \text{ MHz}$	2N5003 2N5005	h <sub>fe</sub>	6.0 7.0		

## SWITCHING CHARACTERISTICS

 $V_{CB} = 10 \ V, \ I_E = 0, \ f = 1 \ MHz$ 

Turn-On Time				
$I_{C} = 5 \text{ A}; I_{B1} = 500 \text{ mA}$		t <sub>on</sub>	0.5	μS
Storage Time	I <sub>B2</sub> = -500 mA	ts	1.4	μS
Fall Time	$V_{BE(OFF)} = 3.7 V$	t <sub>f</sub>	0.5	μS
Turn-Off Time				
$R_L = 6 Ohms$		t <sub>off</sub>	1.5	μS

 $C_{\text{obo}}$ 

pF

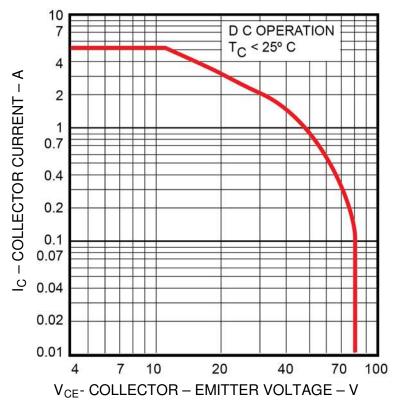
250



ELECTRICAL CHARACTERISTICS  $@T_c = 25^\circ C$  unless otherwise noted. (continued)

SAFE OPERATING AREA (See Figure below and MIL-STD-750, Test Method 3053)

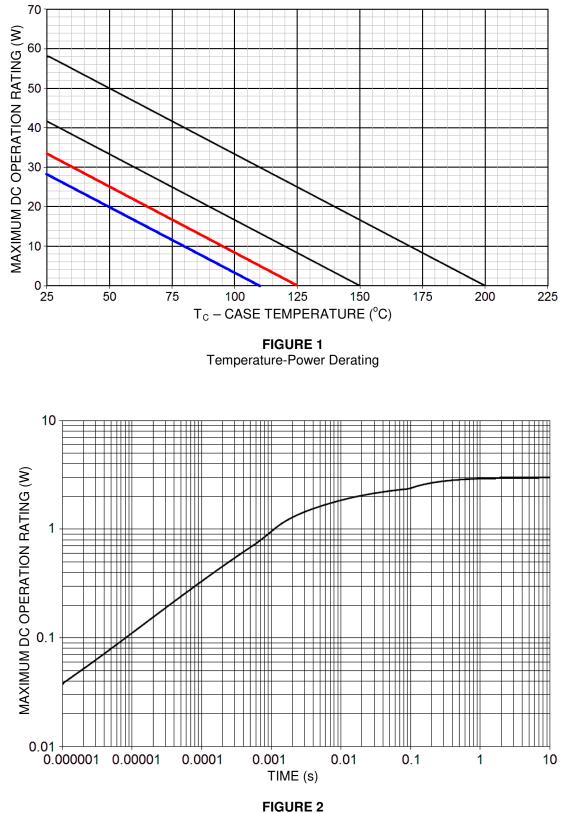
 $\begin{array}{l} \text{DC Tests} \\ T_{C} = +25^{0}\text{C}, \ V_{CE} \ = 0, \ t_{P} = 1 \ \text{second} \ 1 \ \text{Cycle} \\ \hline \text{Test 1} \\ V_{CE} = 12 \ \text{V}, \ I_{C} = 5 \ \text{A} \\ \hline \text{Test 2} \\ V_{CE} = 32 \ \text{V}, \ I_{C} = 1.7 \ \text{A} \\ \hline \text{Test 3} \\ V_{CE} = 80 \ \text{V}, \ I_{C} = 100 \ \text{mA} \end{array}$ 



Maximum safe operating area



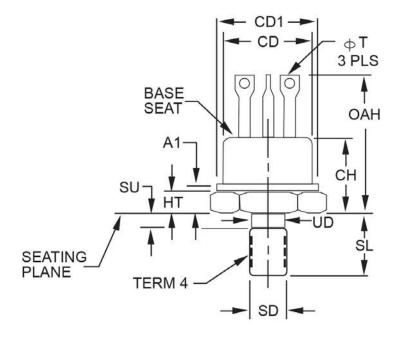
GRAPHS



Thermal Impedance

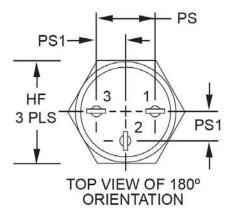


# PACKAGE DIMENSIONS



#### NOTES:

- 1. Dimensions are in inches.
- 2. Millimeters are given for general information only.
- 3. See NSB Handbook H28, "Screw-Thread Standards for Federal Services".
- 4. The orientation of the terminals in relation to the hex flats is not controlled.
- 5. All three terminals.
- 6. The case temperature may be measured anywhere on the seating plane within .125 inch (3.18 mm) of the stud.
- 7. Terminal spacing measured at the base seat only.
- 8. This dimension applies to the location of the center line of the terminals.
- 9. Terminal 1, emitter; terminal 2, base; terminal 3, collector. Collector lead is isolated from the case.
- 10. In accordance with ASME Y14.5M, diameters are equivalent to  $\Phi x$  symbology.



	Dimension				
Symbol	Inches		Millimeters		Notes
-,	Min	Max	Min	Max	
A1		.250		6.35	
CD	.330	.360	8.38	9.14	
CD1	.370	.437	9.40	11.10	
СН	.320	.468	8.13	11.89	
HF	.424	.437	10.77	11.10	
HT	.090	.150	2.29	3.81	
OAH	.575	.763	14.61	19.38	5
PS	.185	.215	4.70	5.46	4, 8
PS1	.090	.110	2.29	2.79	4, 8
SL	.400	.455	10.16	11.56	
SU		.078		1.98	7
Т	.040	.065	1.02	1.65	
UD	.155	.189	3.94	4.80	